


PolyApply The Application of Polymer Electronics to Ambient Intelligence

Organic Electronics: a disruptive technology

ADRIA: Amsterdam meeting, February 2005 


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The technical approach to technology roadmapping: a management view

Bill Eccleston

‘the cornerstone of strong product management
is the technological competence of the manager’

Gordon Moore 1975 (Intel)


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'PolyApply'
(started January 2004)

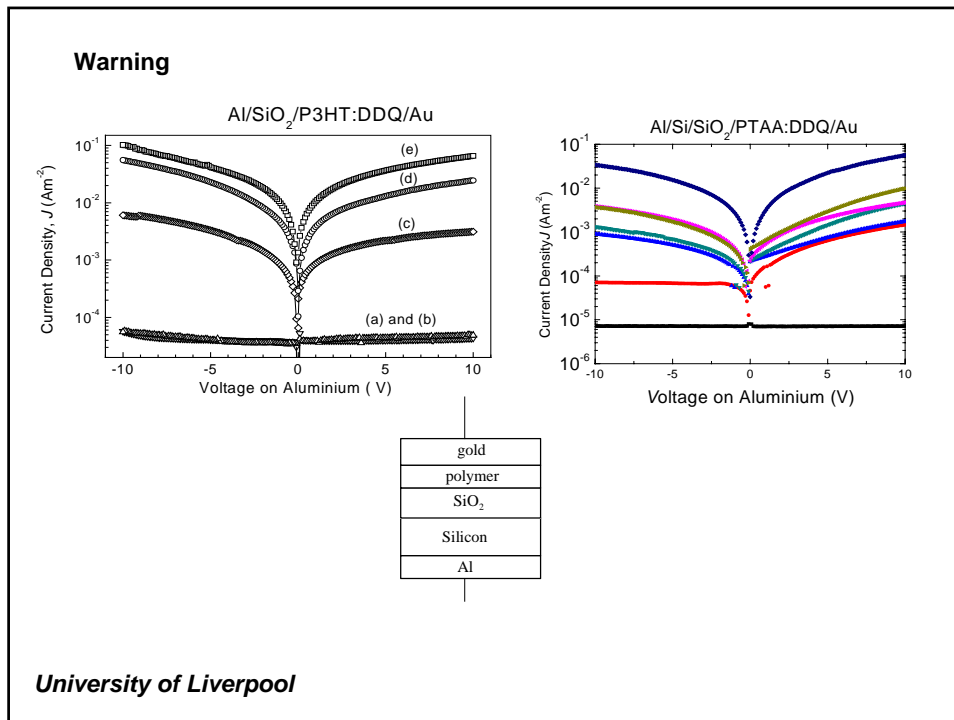
Board Members: ST, Philips,
Motorola, Merck-Avecia, Plastic
Logic, IMEC, Fraunhofers, LETI,
Liverpool University

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- MOS & Bipolar Projects Manager: Caswell
- Technical Consultant: Displays Division GEC (Wembley)
- Chairman: Rytrak Ltd (Equipment for Displays industry)
- Technical Director: UK Light Thin Displays (wholly owned by Akhter Computer Holdings)
- 25 Licensed Patents, 6 in Organics.
- Rankin Professor/ Royal Academician: Liverpool University: (group of 16 people)

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Current status of organic electronics:

- materials have greatly improved in the last three years.
- much improvement still needed.
- manufacturing techniques yet to be agreed, but some advanced form of printing will win.
- currently no scaling rules to give optimum dimensions for roadmaps
- manufacturers of reel to reel print machines are key players: scaling (& hence roadmapping) is also for them
- if tags represent the front-runner and it will be disruptive to item barcode
- air sensitive: packaging problems still have to be resolved
- displays will benefit from very large market for disposable tags.
- low cost organic displays on flexible will be disruptive to other forms of AMCLD
- much depends on the cost of organic materials when produced in bulk.

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Who benefits from roadmapping at such an early stage:

- product managers
- production equipment developers
- Investors
- potential users
- Competitors
- trainers

Consequence of weak/wrong roadmapping

- misdirected development work
- wasted investment funds
- project drag through poor focus
- extension of life of old methods
- unwanted trained people

'rf tags represent the front-runner and it will be disruptive to item barcode'

Why?

Because Wal-mart will insist that almost all the items that it sells have individual rf tags and item suppliers will pay

Why?


**Because that is what they are doing with silicon rf tags for 'slap and ship'
Deadline January 2006**

Why?

Because they have severe logistical problems.

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2004 Baltimore conference of EPC on rf id market: business led by Wal-mart, need to interrogate items within cartons, printable organic tags needed soon. Retail and health sectors leading with military also ahead.


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Technical Roadmapping of rf tags(transistors and diodes)*

- from conduction models develop device physics.
- from device physics determine scaling factors.
- with known performance requirements** scale the device parameters.
- from scaling requirements develop specification of equipment requirements.
- have a standard process which is flexible with respect to the polymer, surface treatments, introduction of a variety organic materials for conductors and diodes. Will provide all the data for implementation of technical roadmap.
- also developing circuit roadmapping

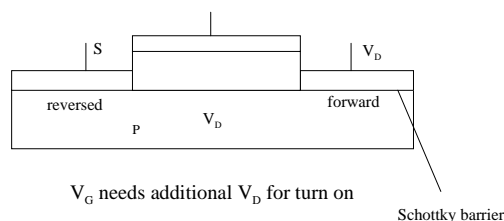
** performance requirements come from business roadmap
* In collaboration with adria

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Scaling Rules: management tool in c-Si

If we multiply channel length by $1/S$,
 we must multiply dopant density by S ,
 we must reduce increased V_T by multiplying gate dielectric thickness by $1/S$,
 but pressure to reduce V_{DD} so make dielectric scaling $1/S^2$ or introduce hi-K dielectrics
 circuit speed $\propto 1/L^2$ so it scales with $1/S^2$
 etc for other parameters: hence Moore's Law.

Non ideal source and drain



This will limit performance: needs to included in scaling rules and models.

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Device Models in conjunction with CEA LETI (and Silvaco)

disordered material:

$$I = \frac{W}{L} \frac{K}{C(C+1)} \frac{C_o^C}{(2\epsilon_o \epsilon_p kT)^m} [(V_G - V_D)^{C+1} - V_G^{C+1}]$$

polycrystalline material:

$$I = \left(\frac{W}{L}\right) \left(\frac{2A}{C(C+1)D^C}\right) [(V_G - V_D)^{C+1} - V_G^{C+1}]$$

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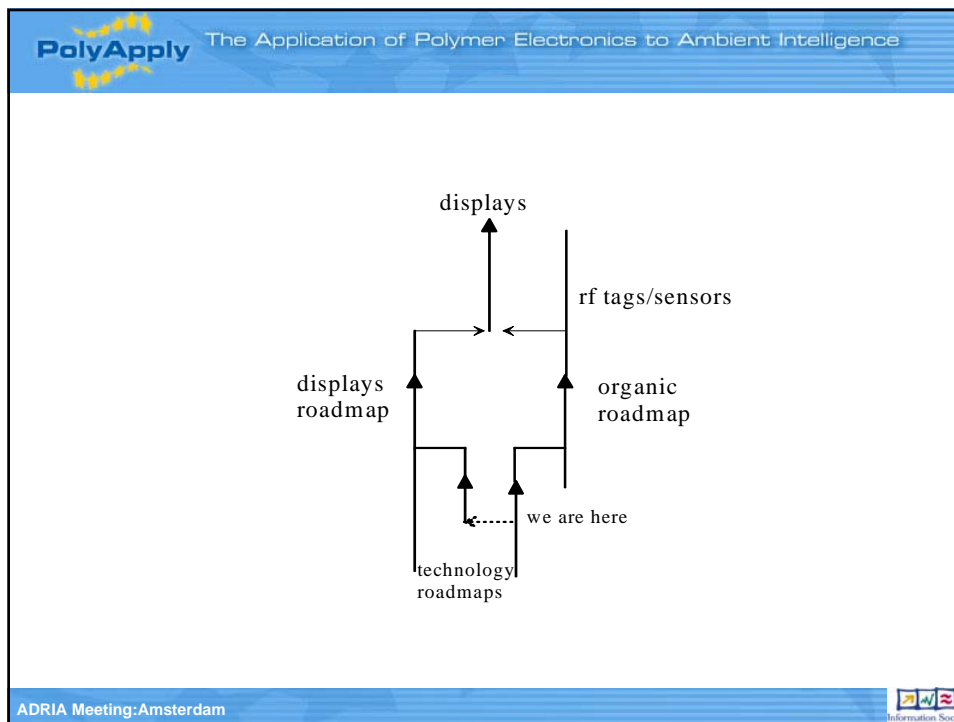
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Scaling Rules: management tool in Organics

- to increase yield and reliability we multiply channel length by 1/S,
- to overcome imperfect contacts must multiply residual stable dopant density by S,
- to reduce off current multiply polymer film thickness by 1/S
- to reduce power reduce V_T by multiplying gate dielectric thickness by 1/S,
- circuit speed $\propto 1/L^2$ so it scales with $1/S^2$

etc for other parameters: hence Moore's Law.

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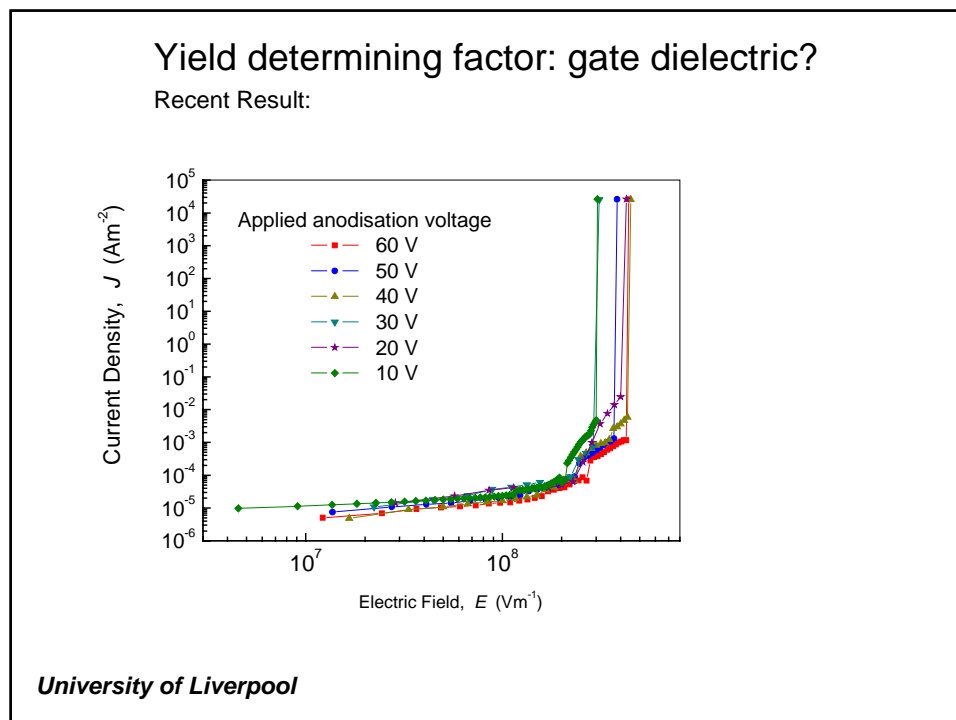
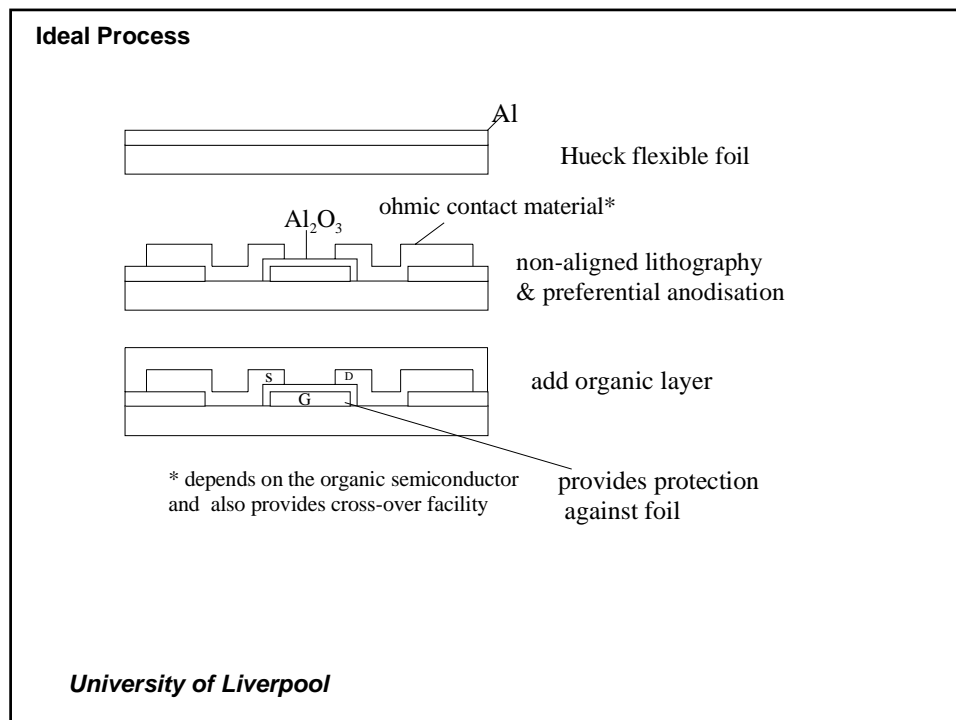
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Conclusions

- organic stability problems are serious
- yield problems are likely to also be critical
- they are different from those experienced with silicon
- good simulation models continue to be produced
- they lead to simple scaling rules for use by management
- they inform, when coupled with a roadmap, a wide range of peripheral suppliers
- we cannot easily fix time scales but take-off will be very rapid and will be disruptive to barcode
- the existence of a strong and growing market in tags will lead to an attempt to disrupt other compatible products (ie displays)
- our main task is to produce a framework for the ongoing development of successive roadmaps

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Calculation of diode or TFT capacitance

Exponential distribution used as approximation to Gaussian distribution of states using an effective temperature T_D gives effective Debye Length L_D :

$$L_D = \left[\frac{\epsilon_0 \epsilon_p k T_D}{q^2 n} \right]^{1/2} \text{ where } \left(\frac{1}{T_D} \right) = \left(\frac{1}{T} \right) - \left(\frac{2}{T_C} \right)$$

• Accumulation layer $n = n_{\text{surface}}$ capacitance = $\epsilon_p \epsilon_0 / L_D$; oxide capacitance $\epsilon_0 \epsilon_d / X_t$

• Drift dominates when $V_{DS} > 10kT_D$ since:

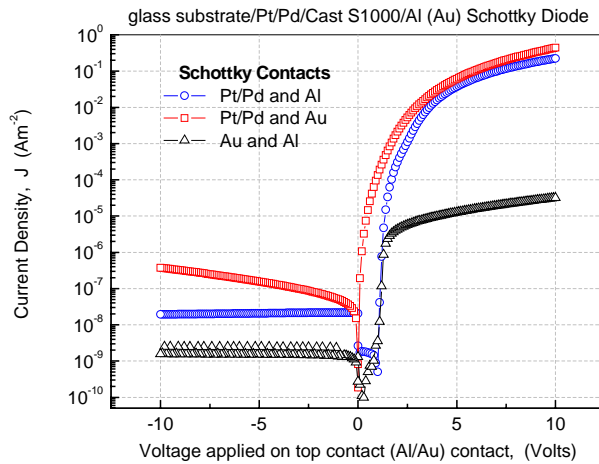
$$J_{diff} = qD \left(\frac{dn}{dx} \right) = qD \left(\frac{n(0)}{L} \right) = q\mu n(0) \left[\frac{kT_D / q}{L} \right]$$

• Abrupt depletion edge approximation applies when classic depletion layer thickness greater than L_D and n in equation for L_D is equal to doping concentration.

• attempting soon to find T_D by measurement of T_C as a function of temperature T for all organics in PolyApply.

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Diode fabrication and device physics



What next?

- continue training and dissemination work
- accelerate scaling activities.
- develop business roadmap.
- develop ideal 'whole-process'
- produce text-book and give trial course to undergraduates
- more work on 'ionic' stability
- complete device models and implement in Silvaco software: for novel circuit development
- produce CCD: currently at mask stage.
- produce dual dielectric memory transistor and find how to use it.
- innovative circuit design.
- plan ICOE 2006

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